



Vincotech

V23990-P829-F108-PM

datasheet

flowPACK 1

1200 V / 50 A

Features

- Compact *flow1* housing
- Trenchstop™ IGBT4 Technology
- Compact and Low Inductance Design
- Built-in NTC

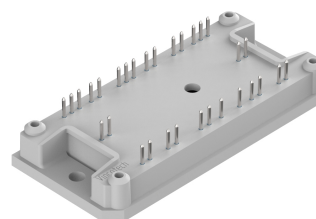
Target applications

- Motor Drive
- Power Generation
- UPS

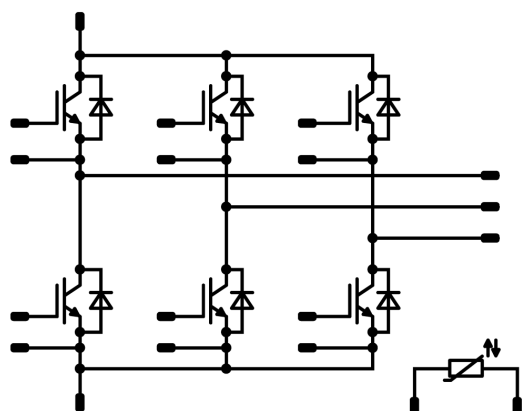
Types

- V23990-P829-F108-PM

flow 1 12 mm housing



Schematic





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Maximum Ratings

$T_j = 25\text{ °C}$, unless otherwise specified

| Parameter | Symbol | Conditions | Value | Unit |
|-----------------------------------|------------|--|----------|--------------------|
| Inverter Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 1200 | V |
| Collector current (DC current) | I_C | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 51 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 150 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 122 | W |
| Gate-emitter voltage | V_{GES} | | ± 20 | V |
| Short circuit ratings | t_{SC} | $V_{GE} = 15\text{ V}$, $V_{CC} = 800\text{ V}$ $T_j = 150\text{ °C}$ | 10 | μs |
| Maximum junction temperature | T_{jmax} | | 175 | $^{\circ}\text{C}$ |

Inverter Diode

| | | | | |
|---------------------------------|------------|---------------------------------------|------|--------------------|
| Peak repetitive reverse voltage | V_{RRM} | | 1200 | V |
| Forward current (DC current) | I_F | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 53 | A |
| Repetitive peak forward current | I_{FRM} | t_p limited by T_{jmax} | 100 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80\text{ °C}$ | 90 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^{\circ}\text{C}$ |

Module Properties

Thermal Properties

| | | | | |
|---|-----------|--|----------------------------|--------------------|
| Storage temperature | T_{stg} | | -40...+125 | $^{\circ}\text{C}$ |
| Operation temperature under switching condition | T_{jop} | | -40...+($T_{jmax} - 25$) | $^{\circ}\text{C}$ |

Isolation Properties

| | | | | |
|----------------------------|------------|-------------------------------------|------------|----|
| Isolation voltage | V_{isol} | DC Test Voltage* $t_p = 2\text{ s}$ | 6000 | V |
| Isolation voltage | V_{isol} | AC Voltage $t_p = 1\text{ min}$ | 2500 | V |
| Creepage distance | | | >12,7 | mm |
| Clearance | | | 7,81 | mm |
| Comparative Tracking Index | CTI | | ≥ 200 | |

*100 % tested in production



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | Values | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|--------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Inverter Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|---------------------|----|------|--------|------------------|------|---------------------|---------------------|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{CE} = V_{GE}$ | | | 0,0017 | 25 | 5,3 | 5,8 | 6,3 | V |
| Collector-emitter saturation voltage | V_{CEsat} | | 15 | | 50 | 25 125 150 | 1,58 | 1,87 2,18 2,3 | 2,07 ⁽¹⁾ | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 1200 | | 25 | | | 1 | μA |
| Gate-emitter leakage current | I_{GES} | | 20 | 0 | | 25 | | | 120 | nA |
| Internal gate resistance | r_g | | | | | | | 4 | | Ω |
| Input capacitance | C_{ies} | $f = 1 \text{ Mhz}$ | 0 | 25 | | 25 | | 2800 | | pF |
| Reverse transfer capacitance | C_{res} | | | | | | | 100 | | pF |
| Gate charge | Q_g | | 15 | | 0 | 25 | | 380 | | nC |

Thermal

| | | | | | | | | | | |
|--|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink ⁽²⁾ | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 0,78 | | K/W |
|--|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|---|----------|-----|----|-----------|--|-----------------|--|-----|
| Turn-on delay time | $t_{d(on)}$ | $R_{gon} = 8 \Omega$ $R_{goff} = 8 \Omega$ | ± 15 | 600 | 50 | 25 150 | | 96,2 100,8 | | ns |
| Rise time | t_r | | | | | 25 150 | | 17,2 23,6 | | ns |
| Turn-off delay time | $t_{d(off)}$ | | | | | 25 150 | | 214 281,4 | | ns |
| Fall time | t_f | | | | | 25 150 | | 86,48 121,84 | | ns |
| Turn-on energy (per pulse) | E_{on} | | | | | 25 150 | | 2,7 4,21 | | mWs |
| Turn-off energy (per pulse) | E_{off} | | | | | 25 150 | | 2,74 4,53 | | mWs |



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | Values | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|--------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Inverter Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|----------------|--|--|----|------------------|------|---------------------|---------------------|----|
| Forward voltage | V_F | | | | 50 | 25 125 150 | 1,35 | 1,73 1,7 1,68 | 2,05 ⁽¹⁾ | V |
| Reverse leakage current | I_R | $V_i = 1200$ V | | | | 25 | | | 10 | μA |

Thermal

| | | | | | | | | | | |
|--|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink ⁽²⁾ | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4$ W/mK (PSX) | | | | | | 1,06 | | K/W |
|--|---------------|---------------------------------------|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--|-----|-----|----|-----------|--|------------------|--|------|
| Peak recovery current | I_{RRM} | $di/dt=3866$ A/μs $di/dt=2820$ A/μs | ±15 | 600 | 50 | 25 150 | | 81,08 84,75 | | A |
| Reverse recovery time | t_{rr} | | | | | 25 150 | | 139,07 315,77 | | ns |
| Recovered charge | Q_r | | | | | 25 150 | | 4,8 9,71 | | μC |
| Reverse recovered energy | E_{rec} | | | | | 25 150 | | 1,79 3,97 | | mWs |
| Peak rate of fall of recovery current | $(di_{rr}/dt)_{max}$ | | | | | 25 150 | | 4803 1209 | | A/μs |



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | Values | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|--------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_C [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Thermistor

Static

| | | | | | | | | | | |
|----------------------------|----------------|------------------------|--|--|--|-----|----|------|---|------|
| Rated resistance | R | | | | | 25 | | 4,7 | | kΩ |
| Deviation of R_{100} | $\Delta_{R/R}$ | $R_{100} = 401 \Omega$ | | | | 100 | -5 | | 5 | % |
| Power dissipation | P | | | | | | | 5 | | mW |
| Power dissipation constant | d | | | | | 25 | | 1,3 | | mW/K |
| B-value | $B_{(25/50)}$ | Tol. $\pm 3 \%$ | | | | | | 3612 | | K |
| B-value | $B_{(25/100)}$ | Tol. $\pm 3 \%$ | | | | | | 3650 | | K |

⁽¹⁾ Value at chip level

⁽²⁾ Only valid with pre-applied Vincotech thermal interface material.



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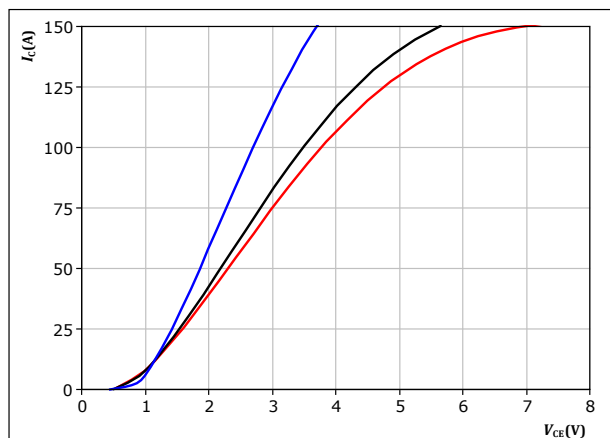
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Inverter Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

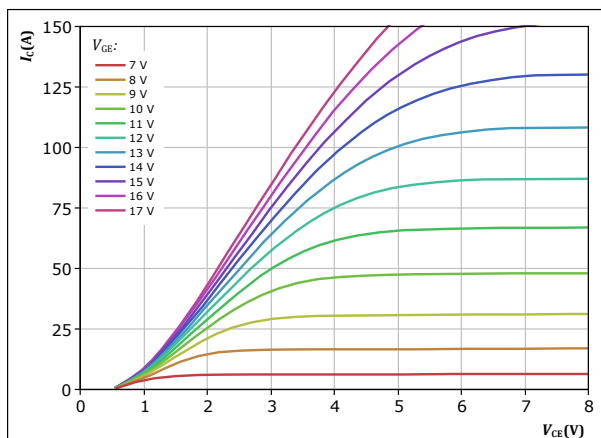


$t_p = 250 \mu s$
 $V_{GE} = 15 V$
 $T_j:$ 25 °C, 125 °C, 150 °C

figure 2. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

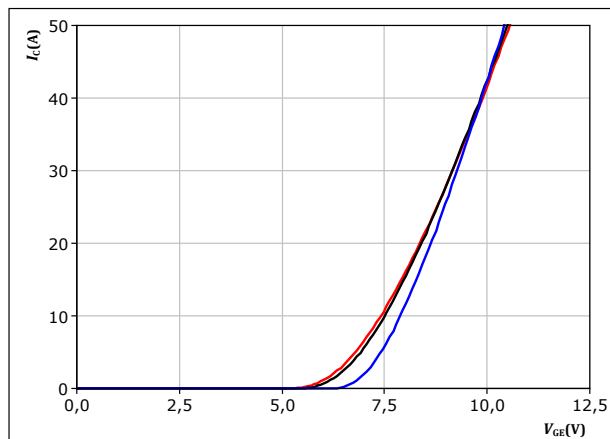


$t_p = 250 \mu s$
 $T_j = 150 \text{ °C}$
 V_{GE} from 7 V to 17 V in steps of 1 V

figure 3. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

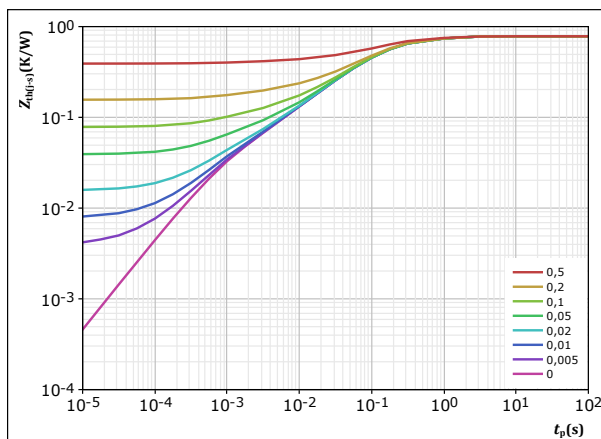


$t_p = 250 \mu s$
 $V_{CE} = 10 V$
 $T_j:$ 25 °C, 125 °C, 150 °C

figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$
 $R_{th(j-s)} = 0.782 \text{ K/W}$
IGBT thermal model values

| $R \text{ (K/W)}$ | $\tau \text{ (s)}$ |
|-------------------|--------------------|
| 1,24E-01 | 9,17E-01 |
| 3,94E-01 | 1,41E-01 |
| 1,70E-01 | 4,90E-02 |
| 6,32E-02 | 9,18E-03 |
| 3,04E-02 | 9,28E-04 |



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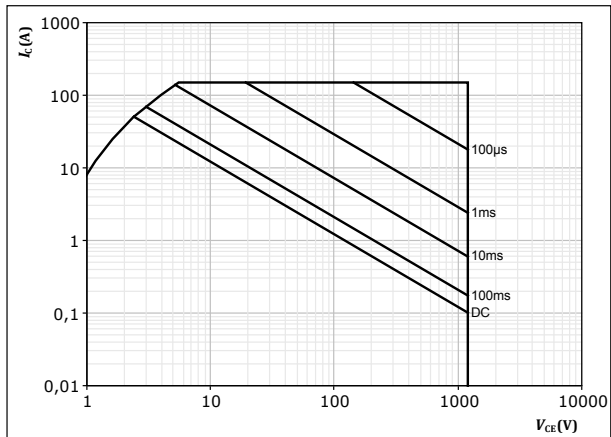
Inverter Switch Characteristics

figure 5.

IGBT

Safe operating area

$$I_C = f(V_{CE})$$



D = single pulse

$T_s = 80$ °C
 $V_{GE} = 15$ V
 $T_j = T_{jmax}$



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Inverter Diode Characteristics

figure 6. FWD

Typical forward characteristics

$$I_F = f(V_F)$$

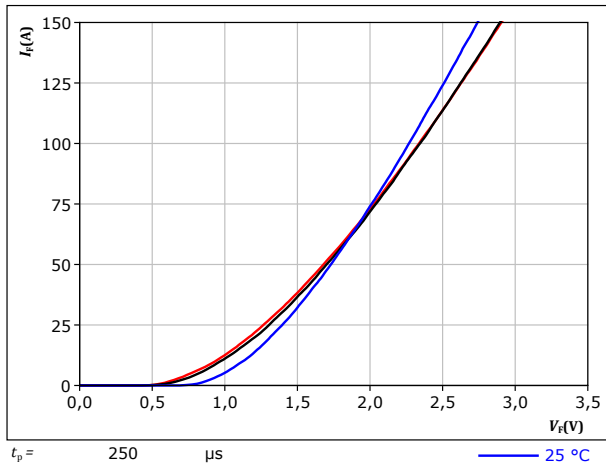
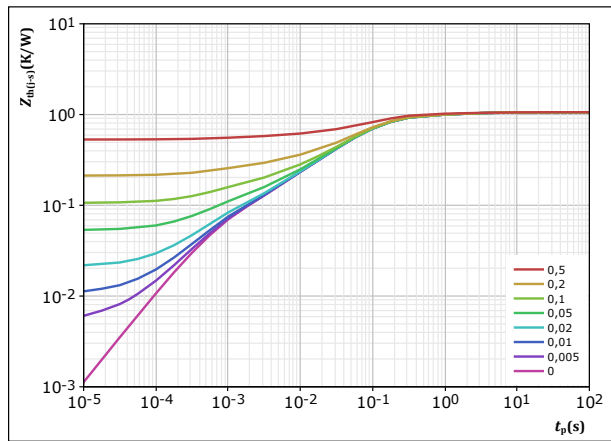


figure 7. FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



| | | |
|--------------------------|------------|-----|
| $D =$ | t_p / T | |
| $R_{th(j-s)} =$ | 1,061 | K/W |
| FWD thermal model values | | |
| R (K/W) | τ (s) | |
| 4,19E-02 | 4,68E+00 | |
| 8,50E-02 | 8,80E-01 | |
| 4,99E-01 | 1,21E-01 | |
| 2,83E-01 | 4,12E-02 | |
| 9,28E-02 | 6,53E-03 | |
| 5,92E-02 | 6,76E-04 | |



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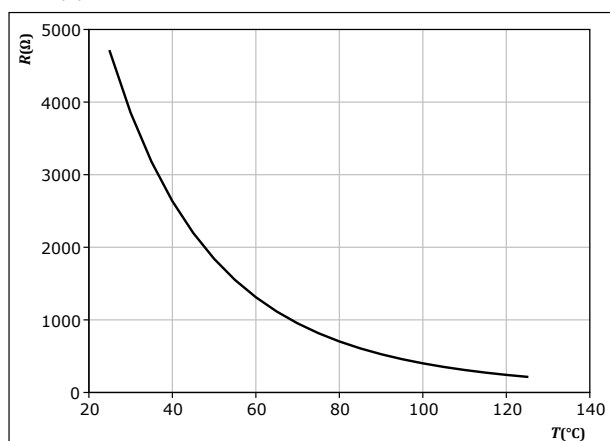
Thermistor Characteristics

figure 8.

Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





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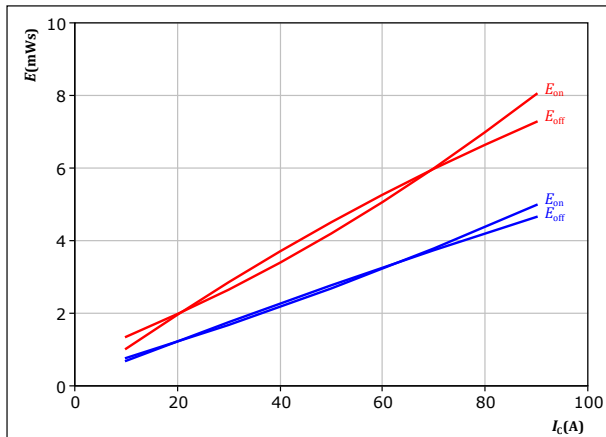
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datasheet

Inverter Switching Characteristics

figure 9. IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

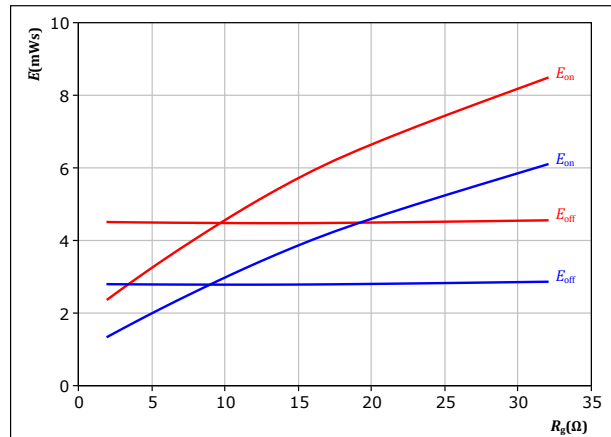
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 8$ Ω
 $R_{goff} = 8$ Ω

T_j : — 25 °C
— 150 °C

figure 10. IGBT

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

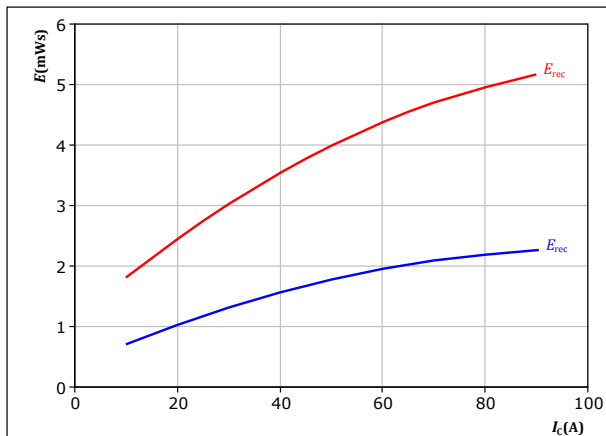
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 50$ A

T_j : — 25 °C
— 150 °C

figure 11. FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

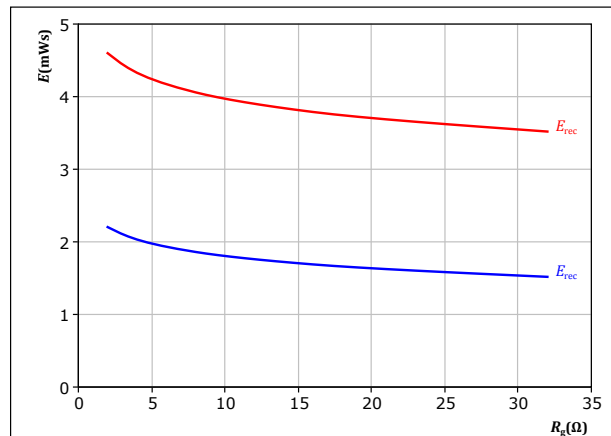
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 8$ Ω

T_j : — 25 °C
— 150 °C

figure 12. FWD

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_C = 50$ A

T_j : — 25 °C
— 150 °C



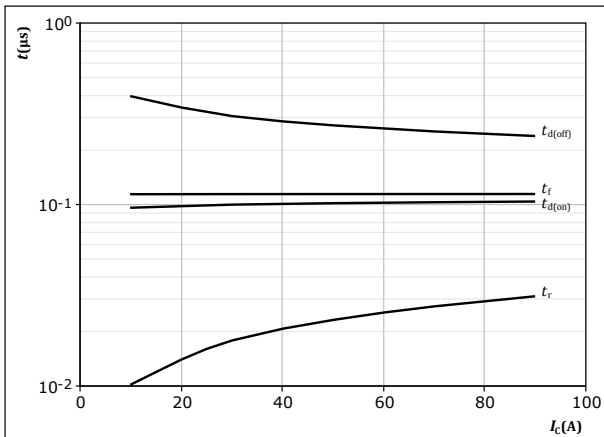
Inverter Switching Characteristics

figure 13.

IGBT

Typical switching times as a function of collector current

$$t = f(I_C)$$



With an inductive load at

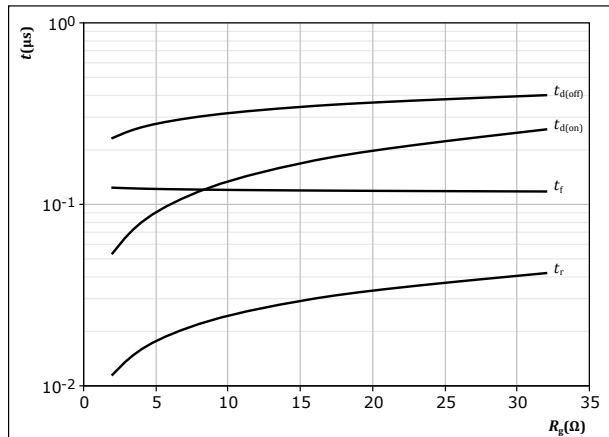
| | | |
|--------------|-----|----|
| $T_j =$ | 150 | °C |
| $V_{CE} =$ | 600 | V |
| $V_{GE} =$ | ±15 | V |
| $R_{gon} =$ | 8 | Ω |
| $R_{goff} =$ | 8 | Ω |

figure 14.

IGBT

Typical switching times as a function of gate resistor

$$t = f(R_g)$$



With an inductive load at

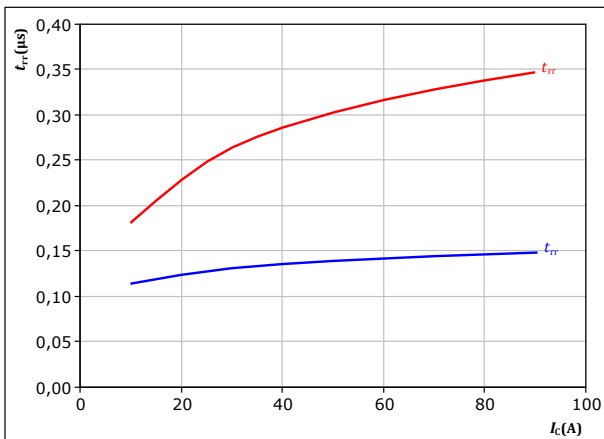
| | | |
|------------|-----|----|
| $T_j =$ | 150 | °C |
| $V_{CE} =$ | 600 | V |
| $V_{GE} =$ | ±15 | V |
| $I_C =$ | 50 | A |

figure 15.

FWD

Typical reverse recovery time as a function of collector current

$$t_{rr} = f(I_C)$$



With an inductive load at

| | | |
|-------------|-----|---|
| $V_{CE} =$ | 600 | V |
| $V_{GE} =$ | ±15 | V |
| $R_{gon} =$ | 8 | Ω |

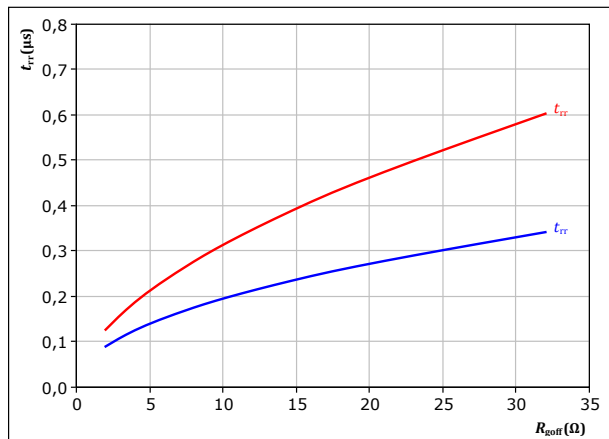
T_j : — 25 °C
— 150 °C

figure 16.

FWD

Typical reverse recovery time as a function of IGBT turn off gate resistor

$$t_{rr} = f(R_{goff})$$



With an inductive load at

| | | |
|------------|-----|---|
| $V_{CE} =$ | 600 | V |
| $V_{GE} =$ | ±15 | V |
| $I_C =$ | 50 | A |

T_j : — 25 °C
— 150 °C



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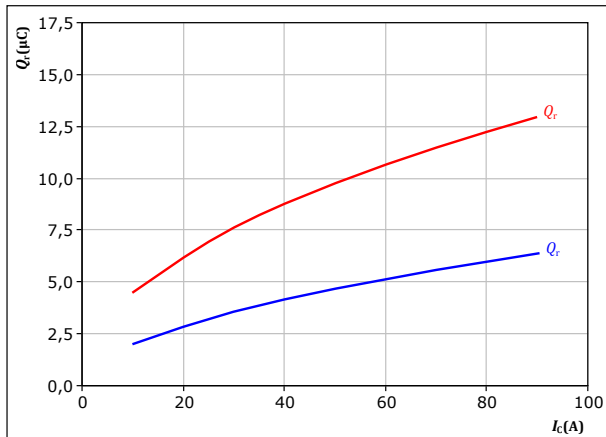
Inverter Switching Characteristics

figure 17.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 8$ Ω

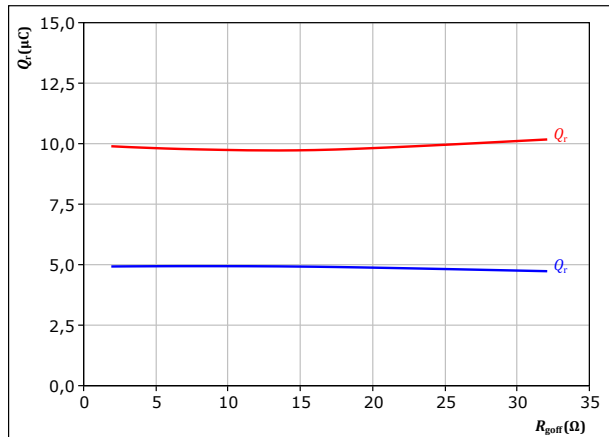
T_j : — 25 °C
— 150 °C

figure 18.

FWD

Typical recovered charge as a function of turn off gate resistor

$$Q_r = f(R_{goff})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 50$ A

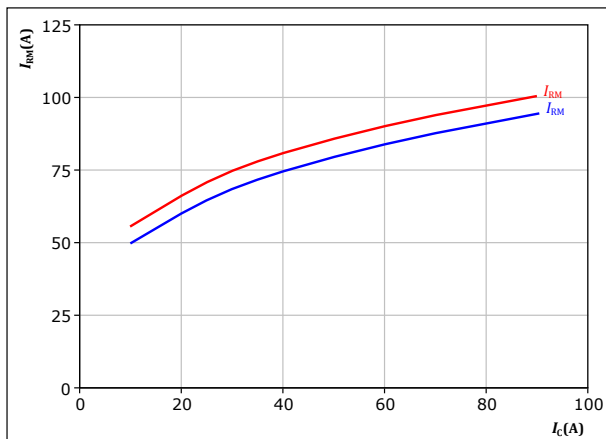
T_j : — 25 °C
— 150 °C

figure 19.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 8$ Ω

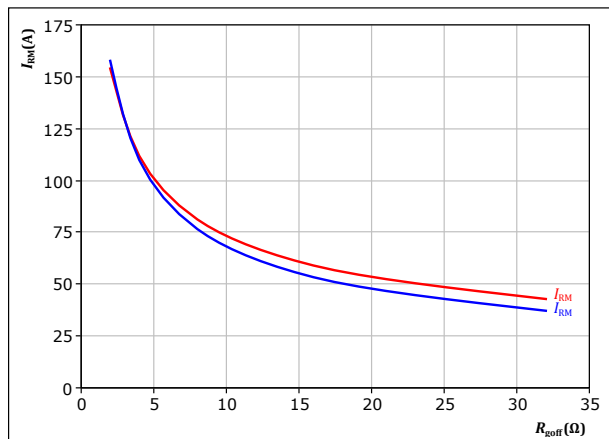
T_j : — 25 °C
— 150 °C

figure 20.

FWD

Typical peak reverse recovery current as a function of turn off gate resistor

$$I_{RM} = f(R_{goff})$$



With an inductive load at

$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 50$ A

T_j : — 25 °C
— 150 °C



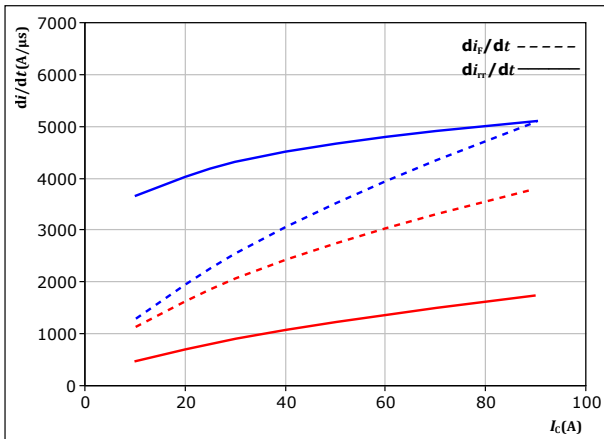
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Inverter Switching Characteristics

figure 21. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_r/dt = f(I_C)$



With an inductive load at

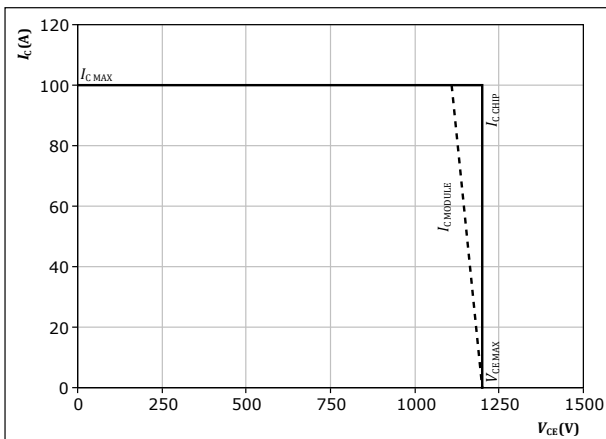
$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{goff} = 8 \text{ } \Omega$

T_j : — 25 °C
— 150 °C

figure 23. IGBT

Reverse bias safe operating area

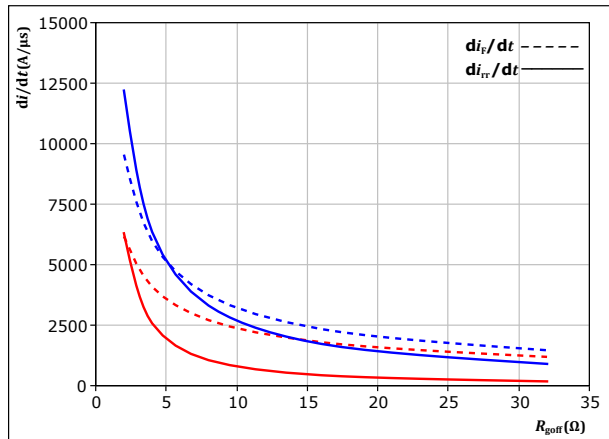
$I_C = f(V_{CE})$



At $T_j = 150 \text{ } ^\circ\text{C}$
 $R_{goff} = 8 \text{ } \Omega$
 $R_{goff} = 8 \text{ } \Omega$

figure 22. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn off gate resistor
 $di_f/dt, di_r/dt = f(R_{goff})$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 50 \text{ A}$

T_j : — 25 °C
— 150 °C



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Inverter Switching Definitions

figure 24. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

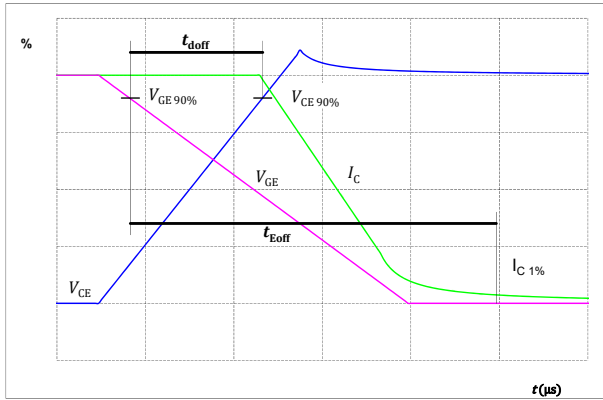


figure 25. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

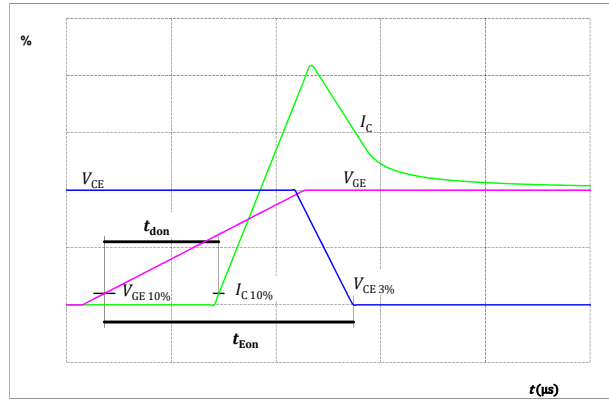


figure 26. IGBT

Turn-off Switching Waveforms & definition of t_f

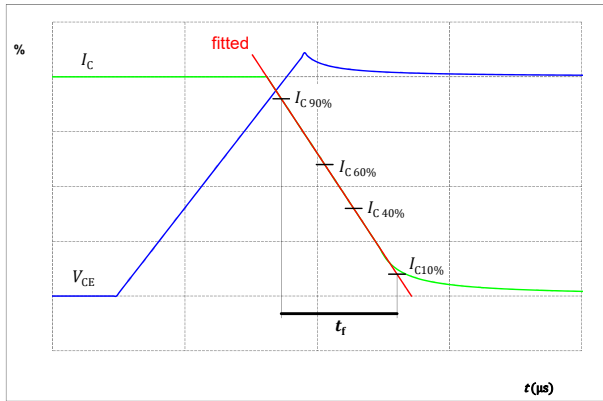
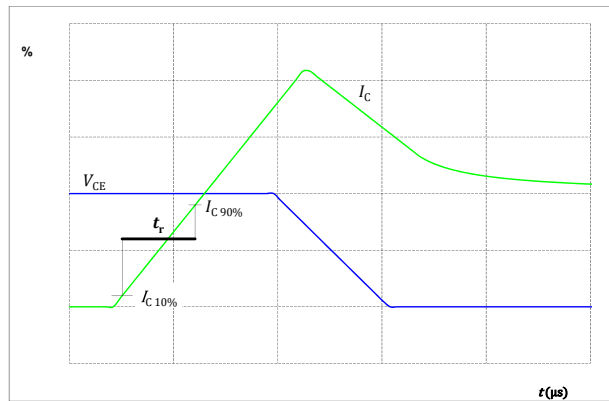


figure 27. IGBT

Turn-on Switching Waveforms & definition of t_r





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Inverter Switching Definitions

figure 28.

FWD

Turn-off Switching Waveforms & definition of t_{rr}

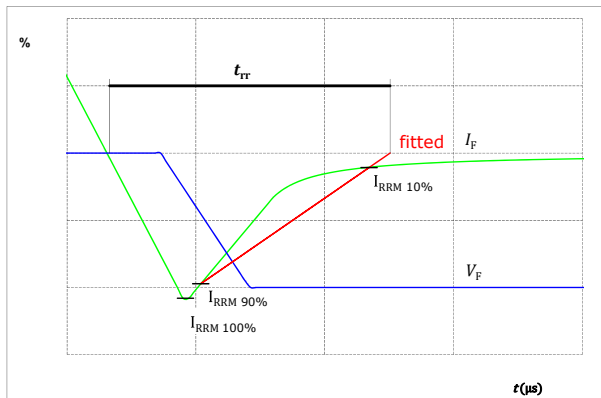
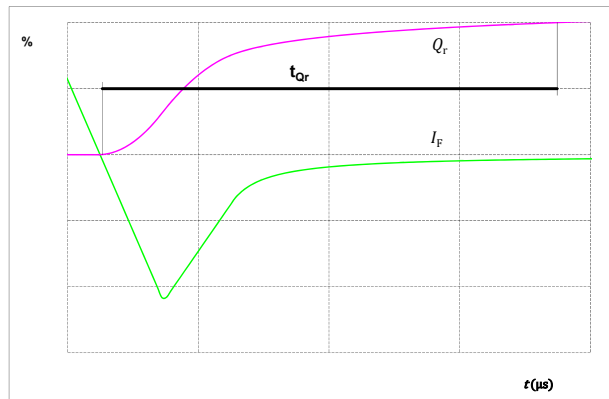


figure 29.

FWD

Turn-on Switching Waveforms & definition of t_{Qr} (t_{Qr} = integrating time for Q_r)





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V23990-P829-F108-PM

datasheet

| Ordering Code | |
|--|-------------------------|
| Version | Ordering Code |
| Without thermal paste | V23990-P829-F108-PM |
| With thermal paste (5,2 W/mK, PTM6000HV) | V23990-P829-F108-/7/-PM |
| With thermal paste (3,4 W/mK, PSX-P7) | V23990-P829-F108-/3/-PM |

| Marking | | | | | | | |
|---------|------------|----------|------------|----------|-----------|------|--------|
| | Text | VIN | Date code | Type&Ver | UL | Lot | Serial |
| | | VIN | WWYY | TTTTTTTV | UL | LLLL | SSSS |
| | Datamatrix | Type&Ver | Lot number | Serial | Date code | | |
| | | TTTTTTTV | LLLL | SSSS | WWYY | | |

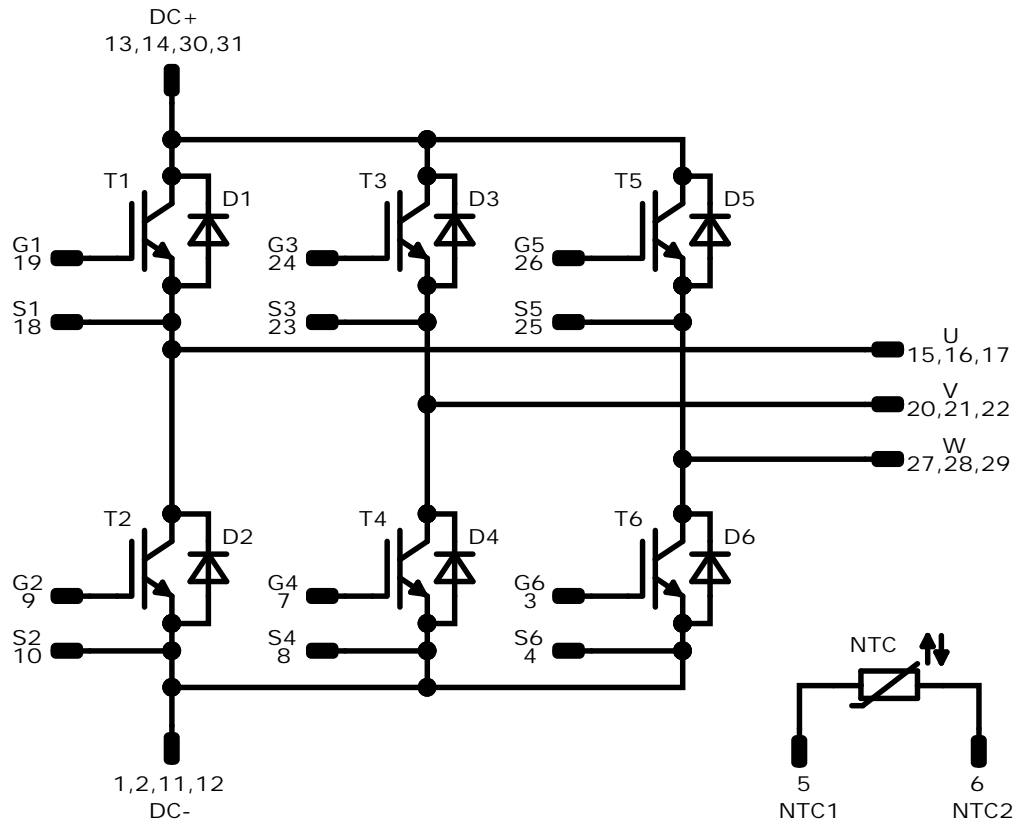
| Outline | | | | |
|----------------|-------|-------|----------|--|
| Pin table [mm] | | | | |
| Pin | X | Y | Function | |
| 1 | 52,6 | 0 | DC- | |
| 2 | 49,9 | 0 | DC- | |
| 3 | 42,65 | 0 | G6 | |
| 4 | 39,65 | 0 | S6 | |
| 5 | 35,15 | 0 | NTC1 | |
| 6 | 28,4 | 0 | NTC2 | |
| 7 | 24 | 0 | G4 | |
| 8 | 21 | 0 | S4 | |
| 9 | 12,2 | 0 | G2 | |
| 10 | 9,2 | 0 | S2 | |
| 11 | 2,7 | 0 | DC- | |
| 12 | 0 | 0 | DC- | |
| 13 | 0 | 14,65 | DC+ | |
| 14 | 2,7 | 14,65 | DC+ | |
| 15 | 0 | 28,6 | U | |
| 16 | 2,7 | 28,6 | U | |
| 17 | 5,4 | 28,6 | U | |
| 18 | 9,6 | 28,6 | S1 | |
| 19 | 12,6 | 28,6 | G1 | |
| 20 | 19,6 | 28,6 | V | |
| 21 | 22,3 | 28,6 | V | |
| 22 | 25 | 28,6 | V | |
| 23 | 29,7 | 28,6 | S3 | |
| 24 | 32,7 | 28,6 | G3 | |
| 25 | 39,7 | 28,6 | S5 | |
| 26 | 42,7 | 28,6 | G5 | |
| 27 | 47,2 | 28,6 | W | |
| 28 | 49,9 | 28,6 | W | |
| 29 | 52,6 | 28,6 | W | |
| 30 | 52,6 | 14,65 | DC+ | |
| 31 | 49,9 | 14,65 | DC+ | |

Tolerance of pinpositions: $\pm 0,5\text{mm}$ at the end of pins
Dimension of coordinate axis is only offset without tolerance



Vincotech


Pinout



Identification

| ID | Component | Voltage | Current | Function | Comment |
|------------------------|------------|---------|---------|-----------------|---------|
| T2, T1, T4, T3, T6, T5 | IGBT | 1200 V | 50 A | Inverter Switch | |
| D1, D2, D3, D4, D5, D6 | FWD | 1200 V | 50 A | Inverter Diode | |
| NTC | Thermistor | | | Thermistor | |



| Packaging instruction | | | | |
|---|------|----------|------|---|
| Standard packaging quantity (SPQ) 100 | >SPQ | Standard | <SPQ | Sample |
| Handling instruction | | | | |
| Handling instructions for <i>flow</i> 1 packages see vincotech.com website. | | | | |
| Package data | | | | |
| Package data for <i>flow</i> 1 packages see vincotech.com website. | | | | |
| Vincotech thermistor reference | | | | |
| See Vincotech thermistor reference table at vincotech.com website. | | | | |
| UL recognition and file number | | | | |
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. | | | |  |

| Document No.: | Date: | Modification: | Pages |
|---------------------------|--------------|--|-------|
| V23990-P829-F108-PM-D5-14 | 12 Sep. 2021 | New Datasheet format, module is unchanged Introduce Rth values with PSX-P7 TIM Separate datasheet for 12mm housing version | |

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.